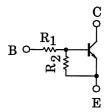
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

## RN1314,RN1315,RN1316 RN1317,RN1318

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2314~RN2318

#### **Equivalent Circuit and Bias Resister Values**



| Type No. | R1 (kΩ) | R2 (kΩ) |
|----------|---------|---------|
| RN1314   | 1       | 10      |
| RN1315   | 2.2     | 10      |
| RN1316   | 4.7     | 10      |
| RN1317   | 10      | 4.7     |
| RN1318   | 47      | 10      |

1. BASE
2. EMITTER
3. COLLECTOR

JEDEC —
EIAJ SC-70
TOSHIBA 2-2E1A

Weight: 0.006g

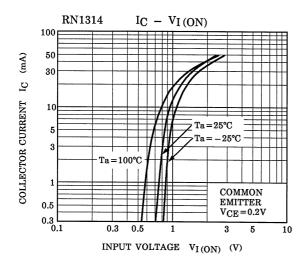
## **Maximum Ratings (Ta = 25°C)**

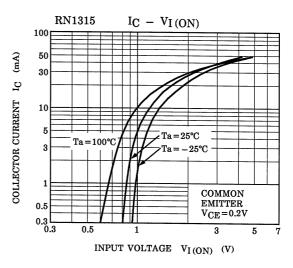
| Characteristic              |             | Symbol           | Rating  | Unit |  |
|-----------------------------|-------------|------------------|---------|------|--|
| Collector-base voltage      | RN1314~1318 | V <sub>CBO</sub> | 50      | V    |  |
| Collector-emitter voltage   | KN1314*1316 | V <sub>CEO</sub> | 50      | V    |  |
|                             | RN1314      |                  | 5       |      |  |
|                             | RN1315      |                  | 6       |      |  |
| Emitter-base voltage        | RN1316      | $V_{EBO}$        | 7       | V    |  |
|                             | RN1317      |                  | 15      |      |  |
|                             | RN1318      |                  | 25      |      |  |
| Collector current           |             | I <sub>C</sub>   | 100     | mA   |  |
| Collector power dissipation | RN1314~1318 | P <sub>C</sub>   | 100     | mW   |  |
| Junction temperature        | KN1314~1318 | Tj               | 150     | °C   |  |
| Storage temperature range   |             | T <sub>stg</sub> | -55~150 | °C   |  |

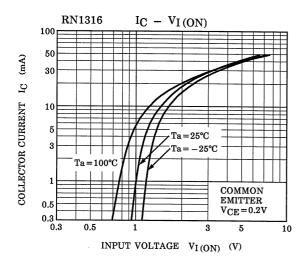


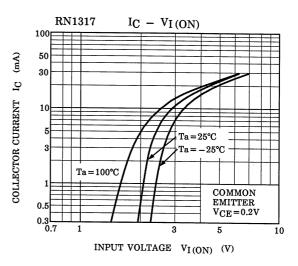
# Electrical Characteristics (Ta = 25°C)

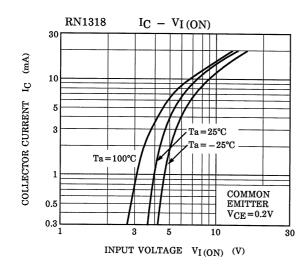
| Characte                             | ristic       | Symbol                | Test<br>Circuit | Test Condition   | Min  | Тур. | Max  | Unit |
|--------------------------------------|--------------|-----------------------|-----------------|--|------|------|------|------|
| Collector cut-off current            | RN1314~1318  | I <sub>CBO</sub>      |                 | V <sub>CB</sub> = 50V, I <sub>E</sub> = 0              | _    | _    | 100  | nA   |
|                                      | RN1314~1318  | I <sub>CEO</sub>      |                 | V <sub>CE</sub> = 50V, I <sub>B</sub> = 0              | _    | _    | 500  | nA   |
| Emitter cut-off current              | RN1314       | I <sub>EBO</sub>      | _               | V <sub>EB</sub> = 5V, I <sub>C</sub> = 0               | 0.35 | _    | 0.65 | mA   |
|                                      | RN1315       |                       |                 | V <sub>EB</sub> = 6V, I <sub>C</sub> = 0               | 0.37 | _    | 0.71 |      |
|                                      | RN1316       |                       |                 | V <sub>EB</sub> = 7V, I <sub>C</sub> = 0               | 0.36 | _    | 0.68 |      |
|                                      | RN1317       |                       |                 | V <sub>EB</sub> = 15V, I <sub>C</sub> = 0              | 0.78 | _    | 1.46 |      |
|                                      | RN1318       |                       |                 | V <sub>EB</sub> = 25V, I <sub>C</sub> = 0              | 0.33 | _    | 0.63 |      |
| DO                                   | RN1314~16,18 | _                     |                 | V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA            | 50   | _    | _    |      |
| DC current gain                      | RN1317       | h <sub>FE</sub>       | _               |  | 30   | _    | _    |      |
| Collector-emitter saturation voltage | RN1314~1318  | V <sub>CE</sub> (sat) | _               | I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA          | _    | 0.1  | 0.3  | ٧    |
|                                      | RN1314       |                       |                 |  | 0.6  | _    | 2.0  | V    |
| Input voltage (ON)                   | RN1315       |                       |                 |  | 0.7  | _    | 2.5  |      |
|                                      | RN1316       | VI (ON)               | _               | V <sub>CE</sub> = 0.2V, I <sub>C</sub> = 5mA           | 0.8  | _    | 2.5  |      |
|                                      | RN1317       |                       |                 |  | 1.5  | _    | 3.5  |      |
|                                      | RN1318       |                       |                 |  | 2.5  | _    | 10.0 |      |
|                                      | RN1314       | Vi (OFF)              |                 | V <sub>CE</sub> = 5V, I <sub>C</sub> = 0.1mA           | 0.3  | _    | 0.9  | V    |
| Input voltage (OFF)                  | RN1315       |                       | _               |  | 0.3  | _    | 1.0  |      |
|                                      | RN1316       |                       |                 |  | 0.3  | _    | 1.1  |      |
|                                      | RN1317       |                       |                 |  | 0.3  | _    | 2.3  |      |
|                                      | RN1318       |                       |                 |  | 0.5  | _    | 5.7  |      |
| Transition frequency                 | RN1314~1318  | f <sub>T</sub>        | _               | V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA            | _    | 250  | _    | MHz  |
| Collector Output capacitance         | RN1314~1318  | C <sub>ob</sub>       | _               | V <sub>CB</sub> = 10V, I <sub>E</sub> = 0,<br>f = 1MHz | _    | 3.0  | 6.0  | pF   |
| Input resistor                       | RN1314       |                       |                 | _  | 0.7  | 1.0  | 1.3  | kΩ   |
|                                      | RN1315       | R <sub>1</sub>        | _               |  | 1.54 | 2.2  | 2.86 |      |
|                                      | RN1316       |                       |                 |  | 3.29 | 4.7  | 6.11 |      |
|                                      | RN1317       |                       |                 |  | 7.0  | 10.0 | 13.0 |      |
|                                      | RN1318       |                       |                 |  | 32.9 | 47.0 | 61.1 |      |
| Resistor ratio                       | RN1314       |                       |                 | _  | _    | 0.1  | _    |      |
|                                      | RN1315       |                       |                 |  | _    | 0.22 | _    |      |
|                                      | RN1316       | $R_1/R_2$             | _               |  | _    | 0.47 | _    |      |
|                                      | RN1317       |                       |                 |  | _    | 2.13 | _    |      |
|                                      | RN1318       |                       |                 |  | _    | 4.7  | _    |      |



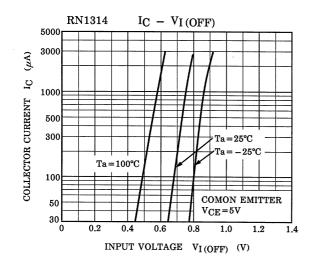


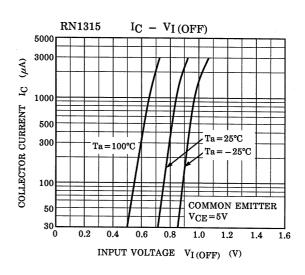


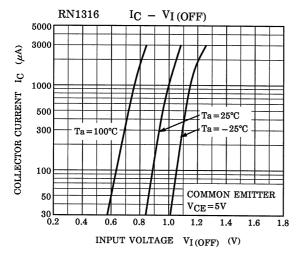


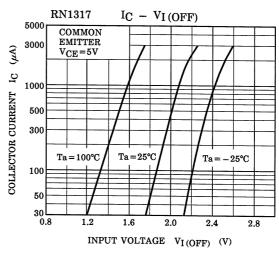


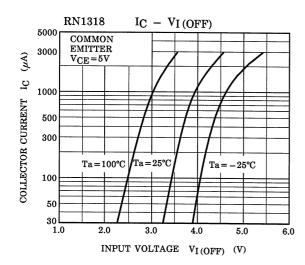
3 2001-06-07



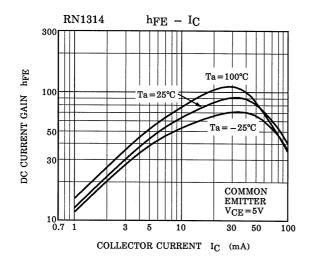


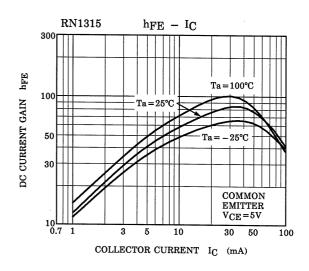


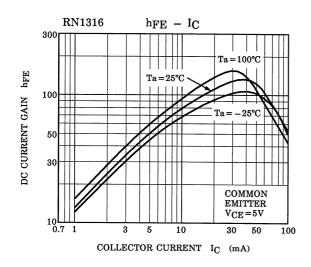


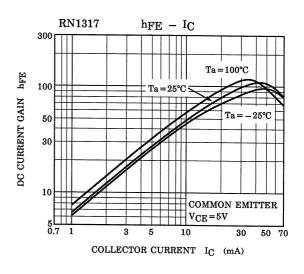


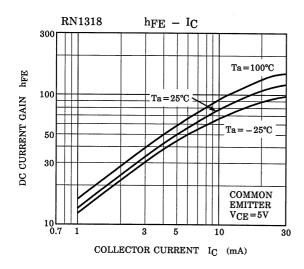
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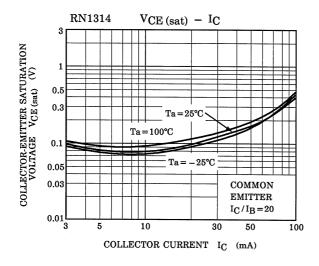


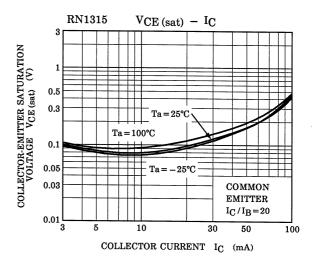


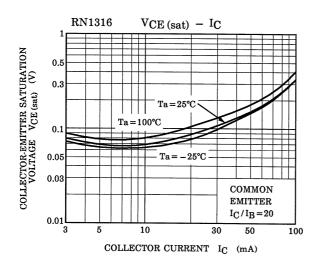


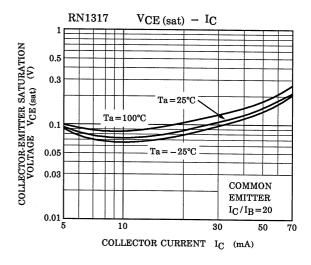


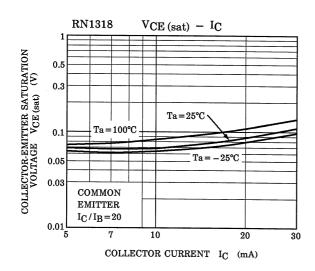
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| Type Name | Marking        |
|-----------|----------------|
| RN1314    | Type Name  X Q |
| RN1315    | Type Name  X S |
| RN1316    | Type Name  XT  |
| RN1317    | Type Name  X U |
| RN1318    | Type Name  X W |

2001-06-07

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